

2SA216300A Datasheet



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DiGi Electronics Part Number 2SA216300A-DG

Manufacturer Panasonic Electronic Components

Manufacturer Product Number 2SA216300A

Description TRANS PNP 20V 0.03A ML3-N2

Detailed Description Bipolar (BJT) Transistor PNP 20 V 30 mA 300MHz 10

0 mW Surface Mount ML3-N2



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DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
2SA216300A	Panasonic Electronic Components
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	30 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
20 V	100mV @ 1mA, 10mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100μΑ	70 @ 1mA, 10V
Power - Max:	Frequency - Transition:
100 mW	300MHz
Operating Temperature:	Mounting Type:
125°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
SC-101, SOT-883	ML3-N2
Base Product Number:	
2SA2163	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	ECCN:
1 (Unlimited)	EAR99
HTSUS:	
8541.21.0075	

Transistors Panasonic

2SA2163

Silicon PNP epitaxial planar type

For high frequency amplification

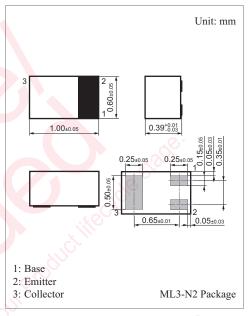
■ Features

- High transition frequency f_T
- Optimum for high-density mounting and downsizing of the equipment for Ultraminiature leadless package

 $0.6 \text{ mm} \times 1.0 \text{ mm} \text{ (height } 0.39 \text{ mm)}$

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	-30	V	
Collector-emitter voltage (Base open)	V _{CEO}	-20	V	
Emitter-base voltage (Collector open)	V_{EBO}	-5	V	
Collector current	$I_{\rm C}$	-30	mA	
Collector power dissipation	P _C	100	mW	
Junction temperature	T_j	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	



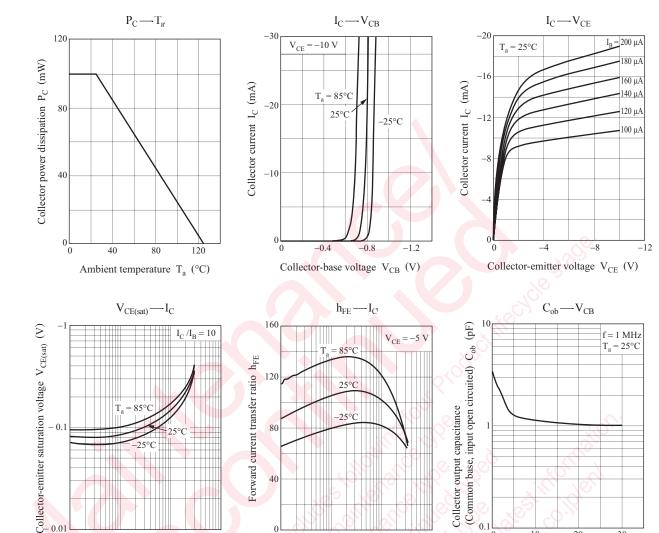
Marking Symbol: 6J

■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Base-emitter voltage	V_{BE}	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	OS X	-0.7		V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -10 \text{ V}, I_{E} = 0$	3 11/0	10	-0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = -20 \text{ V}, I_{B} = 0$	000	0///	-100	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$	10.		-10	μΑ
Forward current transfer ratio	h_{FE}	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	70		220	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$		-0.1		V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_{E} = 1 \text{ mA}, f = 200 \text{ MHz}$	150	300		MHz
Noise figure	NF	$V_{CB} = -10 \text{ V}, I_{E} = 1 \text{ mA}, f = 5 \text{ MHz}$		2.8	4.0	dB
Reverse transfer impedance	Z_{rb}	$V_{CB} = -10 \text{ V}, I_{B} = 1 \text{ mA}, f = 2 \text{ MHz}$		22	50	Ω
Reverse transfer capacitance (Common emitter)	C _{re}	$V_{CB} = -10 \text{ V}, I_{E} = 1 \text{ mA}, f = 10.7 \text{ MHz}$		1.2	2.0	pF

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Panasonic 2SA2163



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Collector current I_C (mA)

Collector-base voltage V_{CB} (V)

2 SJC00336AED

- 0.01 - 0.1

Collector current I_C (mA)

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